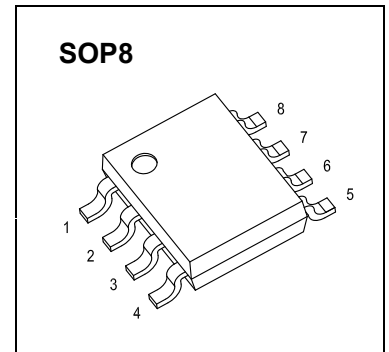


SOP8 Plastic-Encapsulate MOSFETS

CJQ9926 Dual N-Channel MOSFET

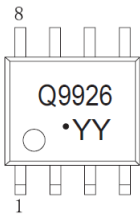
$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
20V	40mΩ@2.5V	4.8A
	30mΩ@4.5V	



FEATURE

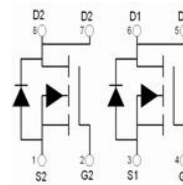
- Advanced trench process technology
- High density cell design for ultra low on-resistance
- High power and current handing capability
- Ideal for Liion battery pack applications

MARKING



Q9926= Device code
 YY=Date Code
 Solid dot = Pin1 indicator
 Solid dot = Green molding compound device,
 if none,the normal device.

Equivalent Circuit



Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current *	I_D	4.8	A
Pulsed Drain Current	I_{DM}	30	A
Power Dissipation *	P_D	1.25	W
Thermal Resistance from Junction to Ambient *	$R_{\theta JA}$	100	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55~+150	$^\circ\text{C}$

* Surface Mounted on 1" x 1" FR4 Board.

MOSFET ELECTRICAL CHARACTERISTICS

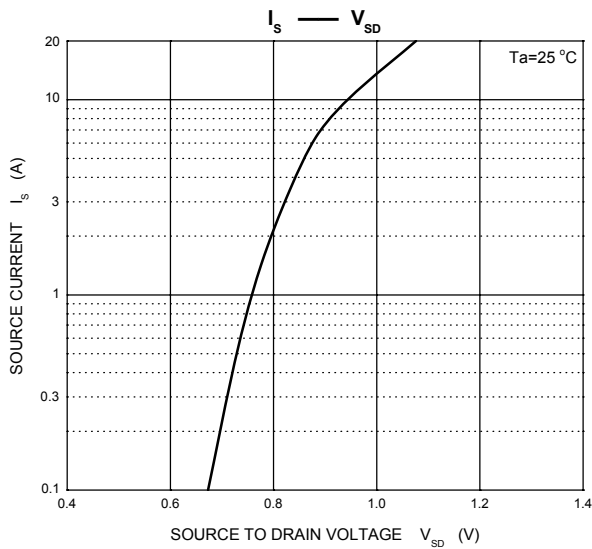
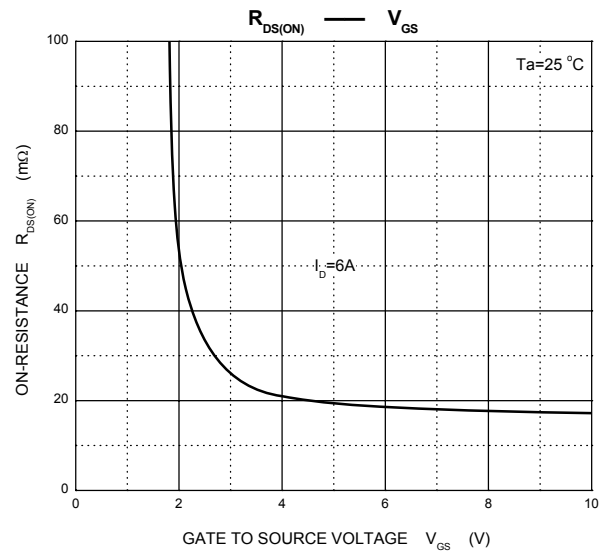
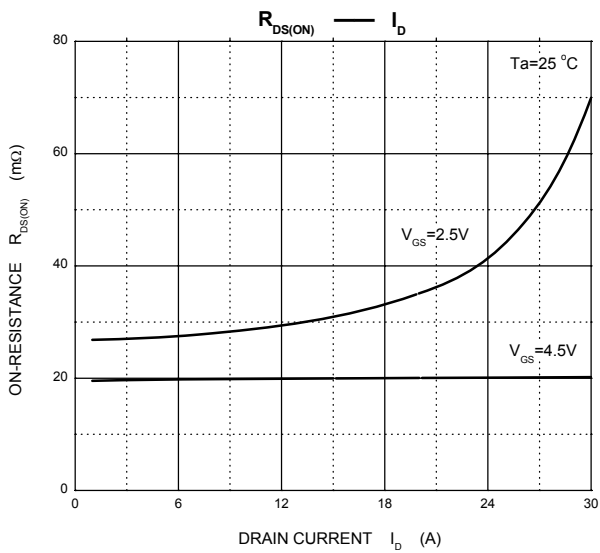
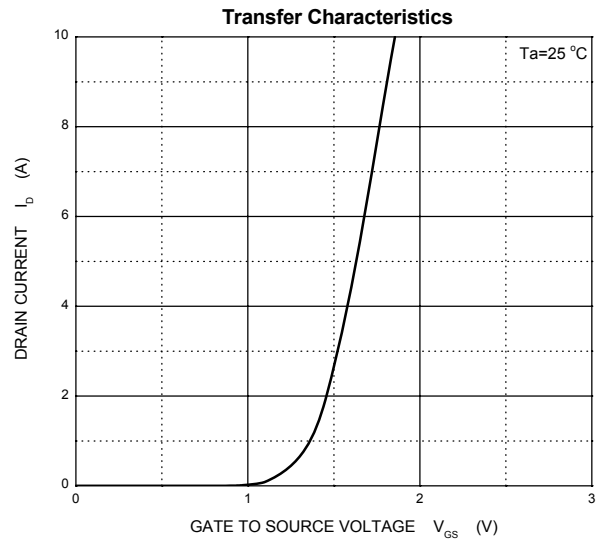
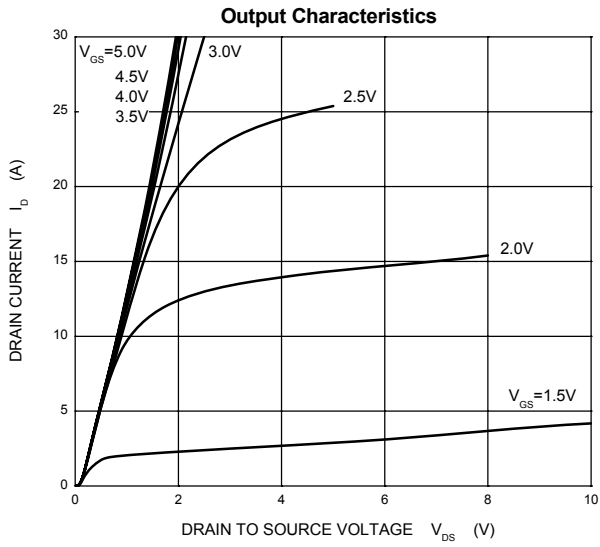
$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 12V, V_{DS} = 0V$			± 100	nA
Gate threshold voltage (note 1)	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.6	1.0	1.2	V
Drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = 2.5V, I_D = 5A$		28	40	m Ω
		$V_{GS} = 4.5V, I_D = 6A$		20	30	m Ω
Forward transconductance (note 1)	g_{FS}	$V_{DS} = 15V, I_D = 6A$	15			S
DYNAMIC CHARACTERISTICS (note 2)						
Input Capacitance	C_{iss}	$V_{DS} = 10V, V_{GS} = 0V,$ $f = 1.0MHz$		640		pF
Output Capacitance	C_{oss}			140		pF
Reverse Transfer Capacitance	C_{rss}			80		pF
SWITCHING CHARACTERISTICS (note 2)						
Turn-on delay time	$t_{d(on)}$	$V_{GEN} = 4.5V, V_{DD} = 15V,$ $R_{GEN} = 6\Omega, I_D = 1A, R_L = 15\Omega$			35	ns
Turn-on rise time	t_r				60	ns
Turn-off delay time	$t_{d(off)}$				75	ns
Turn-off fall time	t_f				30	ns
Total gate charge	Q_g	$V_{DS} = 15V, V_{GS} = 4.5V, I_D = 6A$			20	nC
Gate-source Charge	Q_{gs}			3		nC
Gate-drain Charge	Q_{gd}			3.3		nC
SOURCE-DRAIN DIODE CHARACTERISTICS						
Maximum diode forward current	I_S				1	A
Diode forward voltage (note 1)	V_{SD}	$I_S = 1.7A, V_{GS} = 0V$			1.2	V
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = 1.7A, di/dt = 100A/\mu s$			80	ns

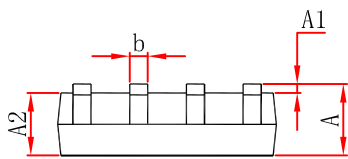
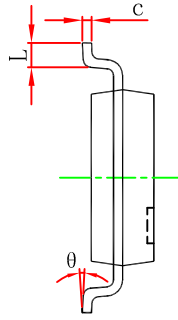
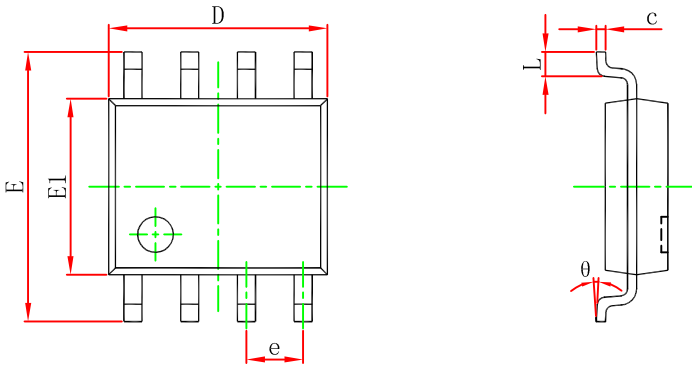
Notes :

1. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
2. Guaranteed by design, not subject to production

Typical Characteristics

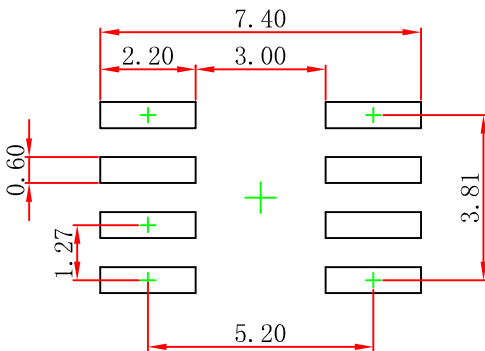


SOP8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

SOP8 Suggested Pad Layout



Note:

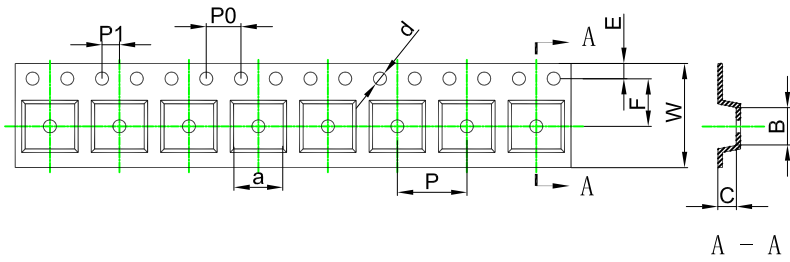
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOP8 Tape and Reel

SOP8 Embossed Carrier Tape



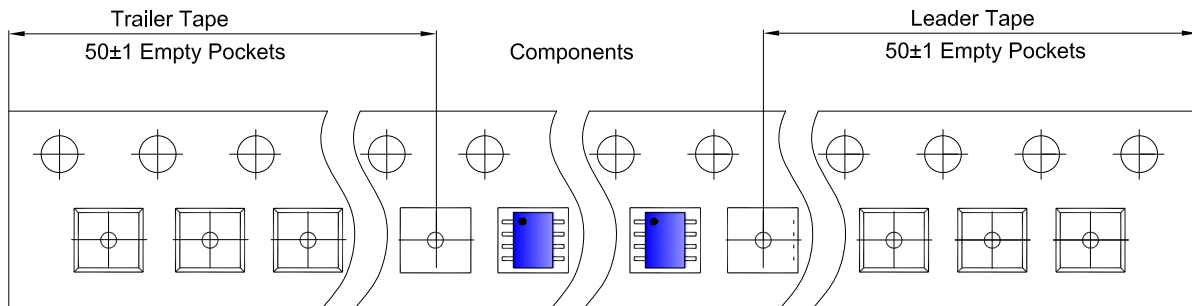
Packaging Description:

SOP8 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 2,500 units per 13" or 33cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

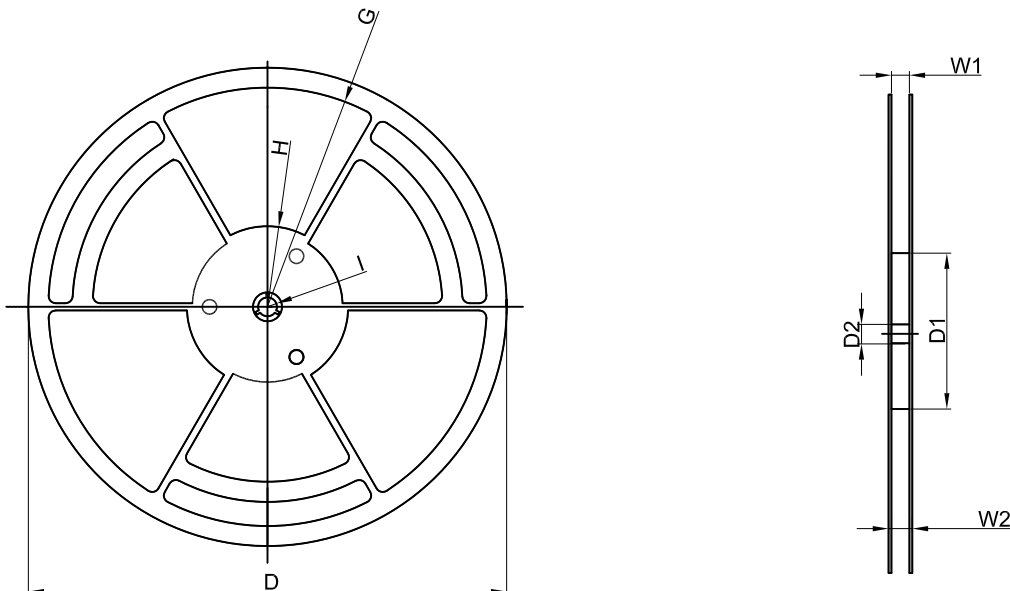
ALL DIM IN mm

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOP8	6.40	5.40	2.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

SOP8 Tape Leader and Trailer



SOP8 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
13" Dia	Ø330.00	100.00	13.00	R151.00	R56.00	R6.50	12.40	17.60

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
4,000 pcs	13 inch	8,000 pcs	360×360×65	64,000 pcs	565×380×390	

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